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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/864,309	05/25/2001	Shigeyuki Uzawa	862.C2239	2803
5514	7590 12/22/2004		EXAMINER	
FITZPATRICK CELLA HARPER & SCINTO 30 ROCKEFELLER PLAZA			JARRETT, RYAN A	
	K, NY 10112		ART UNIT	PAPER NUMBER
			2125	

DATE MAILED: 12/22/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Applicati n No.	Applicant(s)	
	09/864,309	UZAWA ET AL.	
Office Action Summary	Examiner	Art Unit	
	Ryan A. Jarrett	2125	
Th MAILING DATE of this communication a	ppears on the cover sheet w	ith the correspondence address -	
Period for Reply A SHORTENED STATUTORY PERIOD FOR REP THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a re - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the mail earned patent term adjustment. See 37 CFR 1.704(b).	N. 1.136(a). In no event, however, may a eply within the statutory minimum of third will apply and will expire SIX (6) MOI ute, cause the application to become Al	reply be timely filed ty (30) days will be considered timely. ITHS from the mailing date of this communication BANDONED (35 U.S.C. § 133).	ation.
Status		•	
 1) Responsive to communication(s) filed on 10 2a) This action is FINAL. 2b) This action is application is in condition for allow closed in accordance with the practice under 	nis action is non-final. vance except for formal mat	•	s is
Disposition of Claims			
4) Claim(s) 48-58 and 60-62 is/are pending in to 4a) Of the above claim(s) is/are withdom 5) Claim(s) is/are allowed. 6) Claim(s) 48-58 and 60-62 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and	rawn from consideration.		
Application Papers			
9) The specification is objected to by the Examination 10) The drawing(s) filed on is/are: a) and a constant may not request that any objection to the Replacement drawing sheet(s) including the correction. 11) The oath or declaration is objected to by the	ccepted or b) objected to ne drawing(s) be held in abeya ection is required if the drawing	nce. See 37 CFR 1.85(a). (s) is objected to. See 37 CFR 1.12	• •
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the priority docume application from the International Bure * See the attached detailed Office action for a li	ents have been received. ents have been received in A riority documents have been eau (PCT Rule 17.2(a)).	application No received in this National Stage	
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/0	Paper No(Summary (PTO-413) s)/Mail Date nformal Patent Application (PTO-152)	
Paper No(s)/Mail Date	6) Other:	<u>_</u> .	

DETAILED ACTION

Response to Arguments

1. Applicant's arguments filed 11/10/04 have been fully considered but they are not persuasive.

The fact that Hasegawa selectively produces a reduced pressure state and an atmospheric state in an exposure process chamber and a load chamber independently of each other does not preclude the possibility that Hasegawa reads on the current claims. Hasegawa discloses that the gas supplying and discharging system for producing a reduced pressure state and an atmospheric state in the exposure process chamber and the load chamber comprises a single pump and regulator. Thus, the gas used to purge the exposure process chamber comes from the same source (pump) as the gas supplied to the load chamber, and thus is the same type of gas. Hasegawa never discloses or hints that the gas used to purge the exposure process chamber is a different type of gas from that supplied to the load chamber.

The fact that Applicant claims an "inert gas" does not change the structural limitations of this "apparatus claim". The gas supplying system of Hasegawa is fully capable of supplying an inert gas. Nevertheless, Hasegawa does disclose the use of an inert gas, helium (col. 7 lines 29-30).

Regarding the rejection of claims 55-58 in view of 35 U.S.C 103(c), it is noted that Hasegawa et al. U.S. Patent No. 6,406,245 is a divisional of Hasegawa et al. U.S.

Patent No. 5,746,562, published on May 8, 1998. The disclosures of these two patents are the same, at least with respect to the rejection below.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 48-54 and 60-62 are rejected under 35 U.S.C. 102(e) as being anticipated by Hasegawa et al. U.S. Patent No. 6,406,245. Hasegawa et al. discloses an exposure apparatus for exposing a wafer to a pattern, said apparatus comprising: a chamber (e.g., Fig. 3 #101) in which an atmosphere is conditioned to be different from an atmosphere in another apparatus (e.g., Fig. 3 #131) outside of said exposure apparatus and the wafer is exposed to the pattern, the atmosphere in said chamber capable of being purged with an inert gas (e.g., col. 5 lines 56-65); and a port section (e.g., Fig. 3 #102a) through which the wafer is transferred between said chamber and the other apparatus, said port section having a load-lock mechanism (e.g., Fig. 3 #109a, #122a) including a vacuum mechanism for creating a vacuum below atmospheric pressure inside of said port section and a supply mechanism capable of supplying the inert gas into the inside of said port section (e.g., col. 5 lines 56-65);

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wherein said exposure apparatus includes a plurality of said port sections (e.g., Fig. 3 #102a, #102b); wherein said port sections include a first port section for loading the wafer (e.g., Fig. 3 #102a) and a second port section for unloading the wafer (e.g., Fig. 3 #102b); further comprising an interface section (e.g., Fig. 3 #121) for stocking a wafer between said port section and the other apparatus; wherein said interface section includes a load-lock mechanism (e.g., Fig. 3 #122a, #122b); wherein said interface section is shared by a plurality of said port sections (e.g., Fig. 3 #121, #102a, #102b); wherein the other apparatus includes a coating/developing system (e.g., Fig. 3 #131, #132);

a device manufacturing system comprising: an exposure apparatus defined in claim 48 (e.g., Fig. 3 #101); and another apparatus which performs for a wafer at least one of a pre-process (e.g., Fig. 3 #131) and a post-process (e.g., Fig. 3 #132) with respect to an exposure process to be performed by said exposure apparatus; a device manufacturing method comprising a step of exposing a wafer to a pattern using an exposure apparatus defined in claim 48; and developing the exposed wafer (e.g., col. 5 line 66 – col. 7 line 5); a device manufacturing method comprising a step of processing a wafer using a device manufacturing system as defined in claim 60 (e.g., col. 5 line 66 – col. 7 line 5).

Claim Rejections - 35 USC § 103

4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

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(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

5. Claims 55-58 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hasegawa et al. as applied to claim 48 above, and further in view of Ueda et al. U.S. Patent No. 6,319,322. Hasegawa et al. does not explicitly disclose that the port section includes a temperature control mechanism comprising at least one of a heater and a cooler; or that the process chamber includes a temperature control mechanism.

However, such devices are well known in the art. For example, Ueda et al. discloses a substrate processing apparatus comprising an aligner process chamber that includes a temperature control mechanism (e.g., col. 1 lines 50-53); and further comprising a port section that includes a temperature control mechanism that includes at least one of a heater and a cooler (e.g., col. 1 lines 61-64, col. 8 lines 28-37). Therefore, it would have been obvious to one having ordinary skill in the art at the time of the instant application to modify Hasegawa et al. with Ueda et al. since Ueda et al. teaches that a temperature regulating means for regulating the temperature of a substrate held by a port section in accordance with the temperature regulation in an aligner is advantageous so that the substrate can be delivered to the aligner in a state where the temperature of the substrate is regulated closer to the temperature required in the aligner. Accordingly, the temperature of the substrate can be more accurately regulated in the aligner in a shorter time, so that circuit patterns can be accurately transferred, and throughput can be improved by speeding up the processing (e.g., col. 1 line 65 – col. 2 line 8).

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Conclusion

6. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ryan A. Jarrett whose telephone number is (571) 272-3742. The examiner can normally be reached on 10:00-6:30 M-F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Leo Picard can be reached on (571) 272-3749. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Ryan A. Jarrett Examiner Art Unit 2125

L. P. Pm

12/12/04

LEO PICARD SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2100